NSN 5961-00-781-2809

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-781-2809 **Inclosure Material:** Metal **Overall Length:** 3.625 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 1.218 inches and 1.250 inches **Thread Size:** 0.750 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakover voltage, dc **Current Rating Per Characteristic:** 235.00 amperes source cutoff current of standard range **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 3 uninsulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig:

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